

KSC2330

Color TV Chroma Output

- Collector-Base Voltage: V_{CBO}=300V
 Current Gain Bandwidth Product: f_T=50MHz (TYP.)



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	300	V
V _{CEO}	Collector-Emitter Voltage	300	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current	100	mA
P _C	Collector Power Dissipation	1	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_a =25°C unless otherwise notd

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	300			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	300			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=100\mu A, I_C=0$	7			V
I _{CBO}	Collector Cut-off Current	V _{CB} =200V, I _E =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =20mA	40		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA			0.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =30V, I _C =10mA		50		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		4		pF

h_{FE} Classification

Classification	R	0	Y
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Characteristics

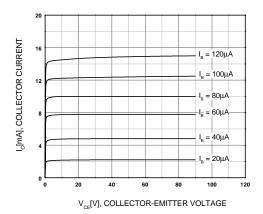


Figure 1. Static Characteristic

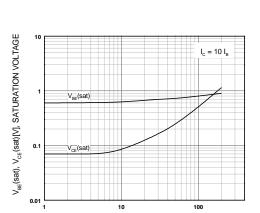


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

 $\rm I_{\rm c}[mA]$, COLLECTOR CURRENT

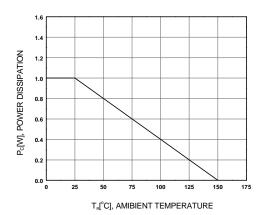


Figure 5. Power Derating

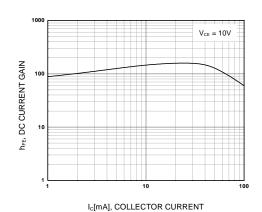


Figure 2. DC current Gain

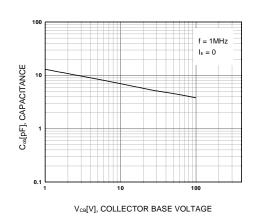
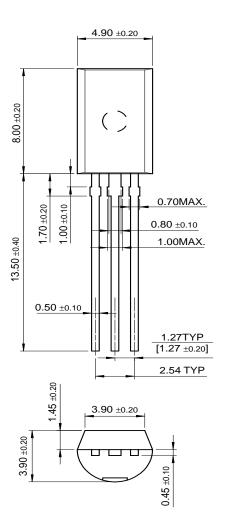
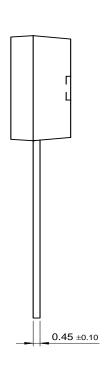


Figure 4. Collector Output Capacitance

Package Demensions

TO-92L





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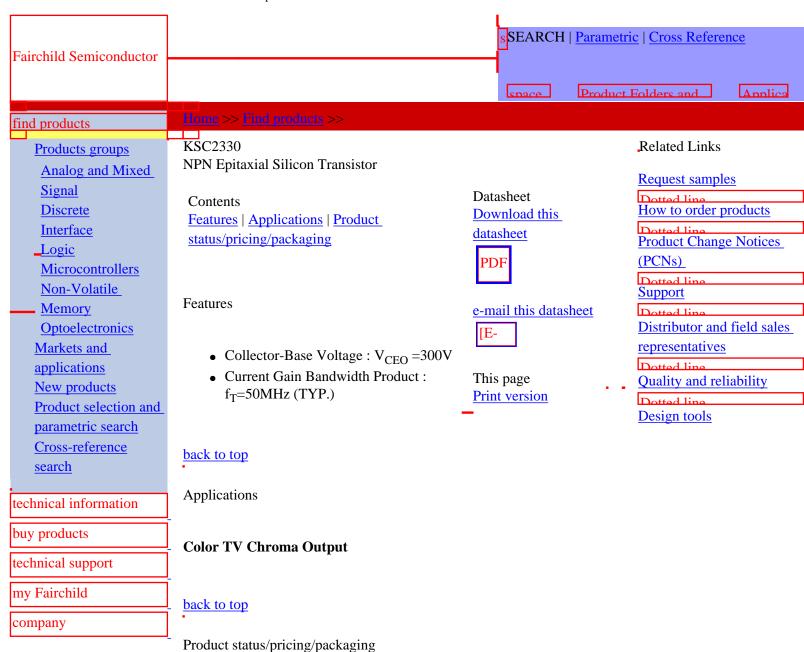
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Product	Product status	Pricing*	Package type	Leads	Packing method
KSC2330OTA	Full Production	\$0.08	TO-92	3	TAPE REEL
KSC2330YH2TA	Full Production	\$0.08	TO-92	3	TAPE REEL
KSC2330RBU	Full Production	\$0.08	TO-92	3	BULK
KSC2330RTA	Full Production	\$0.08	TO-92	3	TAPE REEL
KSC2330OSHTA	Full Production	\$0.08	TO-92	3	TAPE REEL
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KSC2330OBU	Full Production	\$0.08	TO-92	3	BULK
KSC2330ONBU	Full Production	\$0.08	TO-92	3	BULK
KSC2330YTA	Full Production	\$0.08	TO-92	3	TAPE REEL
KSC2330YNBU	Full Production	\$0.08	TO-92	3	BULK

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